

## Features

- Low switching losses
- Maximum junction temperature 175°C
- Positive temperature coefficient
- High ruggedness, temperature stable
- High short circuit capability(5μs)
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Applications

- High frequency switching application
- Medical applications
- Uninterruptible power supply
- Motion/servo control

## Maximum Ratings

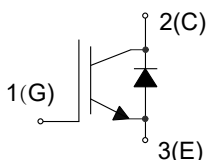
- Operating Junction Temperature Range : -40°C to +175°C
- Storage Temperature Range: -55°C to +150°C
- IGBT Thermal Resistance: 0.49°C/W Junction to Case
- Diode Thermal Resistance: 1.05°C/W Junction to Case
- Thermal Resistance: 40°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit	
Collector-Emitter Voltage	$V_{CE}$	650	V	
DC Collector Current <sup>(2)</sup>	$I_C$	$T_C=25^\circ\text{C}$	80	
		$T_C=100^\circ\text{C}$	40	
Pulsed Collector Current <sup>(3)</sup> $V_{GE}=15\text{V}$	$I_{CM}$	160	A	
Diode Forward Current <sup>(2)</sup>	$I_F$	$T_C=25^\circ\text{C}$	60	
		$T_C=100^\circ\text{C}$	30	
Diode Pulsed Current <sup>(3)</sup>	$I_{F,pulse}$	120	A	
Gate-Emitter Voltage	$V_{GE}$	$\pm 20$	V	
Transient Gate-Emitter Voltage		$\pm 30$		
Short Circuit Withstand Time $V_{GE}=15\text{V}, V_{CC}=400\text{V}, V_{CEM}\leq 650\text{V}$	$t_{SC}$	5	μs	
Power Dissipation	$T_j=25^\circ\text{C}$	$P_D$	306	W

Note:

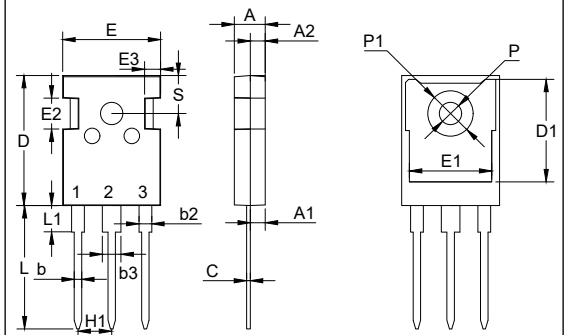
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. Limited by  $T_{Jmax}$ .
3.  $T_p$  limited by  $T_{Jmax}$ .

## Internal Structure



# Trench and Field Stop IGBT 650V 40A

## TO-247AB



### DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.189	0.205	4.80	5.20	
A1	0.087	0.103	2.21	2.61	
A2	0.073	0.085	1.85	2.15	
b	0.039	0.055	1.00	1.40	
b2	0.075	0.087	1.91	2.21	
C	0.020	0.028	0.50	0.70	
D	0.815	0.839	20.70	21.30	
D1	0.640	0.663	16.25	16.85	
E	0.610	0.634	15.50	16.10	
E1	0.512	0.535	13.00	13.60	
E2	0.189	0.205	4.80	5.20	
E3	0.091	0.106	2.30	2.70	
L	0.772	0.796	19.62	20.22	
L1	-	0.169	-	4.30	
P	0.134	0.150	3.40	3.80	Φ
P1		0.287	-	7.30	Φ
S		0.242		6.15	TYP
H1		0.214		5.44	TYP
b3	0.110	0.126	2.80	3.20	

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	$V_{GE}=0V, I_C=250\mu A$	650			V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=40A, T_J=25^\circ C$		1.95	2.40	V
		$V_{GE}=15V, I_C=40A, T_J=125^\circ C$		2.30		
		$V_{GE}=15V, I_C=40A, T_J=150^\circ C$		2.40		
G-E Threshold Voltage	$V_{GE(th)}$	$I_C=430\mu A, V_{GE}=V_{CE}$	4.1	5.1	6.1	V
C-E Leakage Current	$I_{CES}$	$V_{CE}=650V, V_{GE}=0V, T_J=25^\circ C$			0.25	mA
		$V_{CE}=650V, V_{GE}=0V, T_J=150^\circ C$			4.00	
G-E Leakage Current	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$			100	nA
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{ies}$	$V_{CE}=25V, V_{GE}=0V, f=1MHz$		1.56		nF
Reverse Transfer Capacitance	$C_{res}$			0.06		
Gate Charge	$Q_g$	$V_{CC}=300V, I_C=40A, V_{GE}=15V$		0.16		$\mu C$
Short Circuit Collector Current	$I_{sc}$	$V_{GE}=15V, t_{sc}\leq 5\mu s, V_{CC}=300V, T_J\leq 150^\circ C$		200		A
<b>IGBT Switching Characteristics</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=400V, I_C=40A, V_{GE}=0\sim 15V, R_G=10\Omega, L_s=60nH, T_J=25^\circ C$		12		ns
Rise Time	$t_r$			31		
Turn-Off Delay Time	$t_{d(off)}$			124		
Fall Time	$t_f$			54		
Turn-On Energy	$E_{on}$			1.55		mJ
Turn-Off Energy	$E_{off}$			0.59		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=400V, I_C=40A, V_{GE}=0\sim 15V, R_G=10\Omega, L_s=60nH, T_J=125$		11		ns
Rise Time	$t_r$			30		
Turn-Off Delay Time	$t_{d(off)}$			132		
Fall Time	$t_f$			84		
Turn-On Energy	$E_{on}$			1.57		mJ
Turn-Off Energy	$E_{off}$			0.83		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=400V, I_C=40A, V_{GE}=0\sim 15V, R_G=10\Omega, L_s=60nH, T_J=150$		11		ns
Rise Time	$t_r$			30		
Turn-Off Delay Time	$t_{d(off)}$			137		
Fall Time	$t_f$			102		
Turn-On Energy	$E_{on}$			1.6		mJ
Turn-Off Energy	$E_{off}$			0.88		

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Diode Static Characteristics</b>						
Diode Forward Voltage	$V_F$	$I_F=30A, T_J=25^\circ C$		2.00	2.50	V
		$I_F=30A, T_J=125^\circ C$		1.95		
		$I_F=30A, T_J=150^\circ C$		1.95		
<b>Diode Dynamic Characteristics</b>						
Reverse Recovery Current	$I_{rr}$	$V_R=400V, I_F=40A,$ $di/dt=-410A/\mu s, T_J=25^\circ C$		9		A
Reverse Recovery Charge	$Q_{rr}$			0.155		$\mu C$
Diode Reverse Recovery Time	$t_{rr}$			29		ns
Reverse Recovery Energy	$E_{rec}$			0.09		mJ
Reverse Recovery Current	$I_{rr}$	$V_R=400V, I_F=40A,$ $di/dt=-410A/\mu s, T_J=125^\circ C$		13		A
Reverse Recovery Charge	$Q_{rr}$			0.824		$\mu C$
Diode Reverse Recovery Time	$t_{rr}$			112		ns
Reverse Recovery Energy	$E_{rec}$			0.15		mJ
Reverse Recovery Current	$I_{rr}$	$V_R=400V, I_F=40A,$ $di/dt=-410A/\mu s, T_J=150^\circ C$		13		A
Reverse Recovery Charge	$Q_{rr}$			1.16		$\mu C$
Diode Reverse Recovery Time	$t_{rr}$			140		ns
Reverse Recovery Energy	$E_{rec}$			0.23		mJ

Curve Characteristics

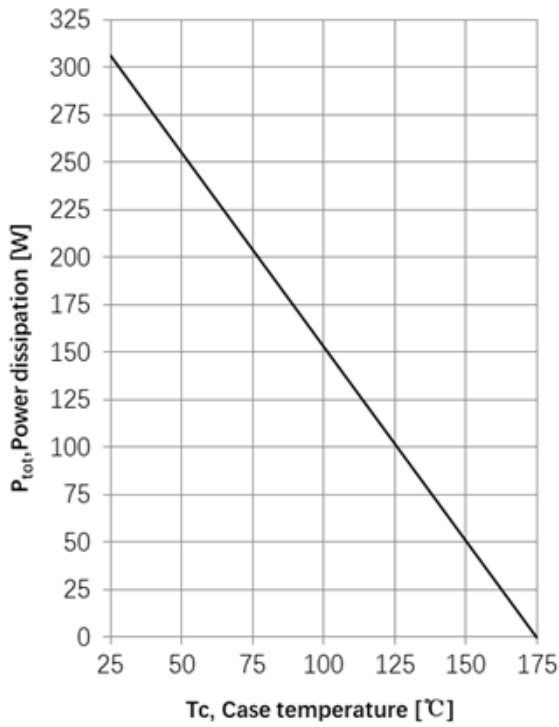


Fig1. Power dissipation as a function of case temperature ( $T_j \leq 175^\circ\text{C}$ )

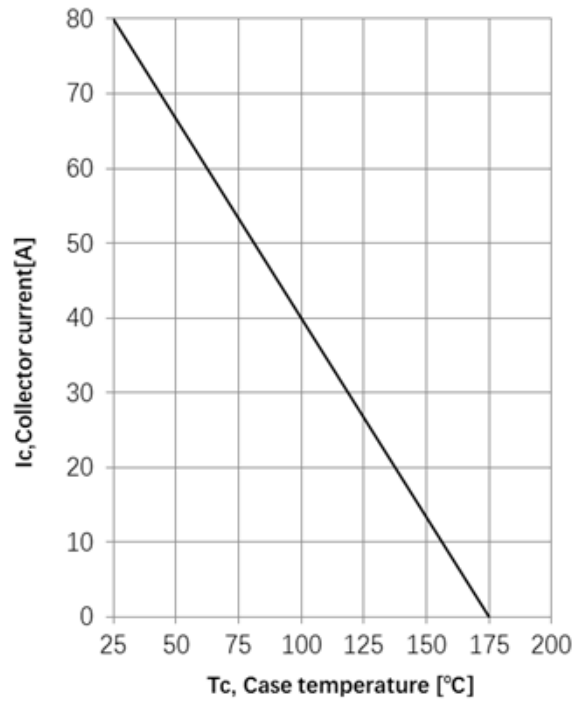


Fig2. Collector current as a function of case temperature ( $V_{ge} \geq 15\text{V}$ ,  $T_j \leq 175^\circ\text{C}$ )

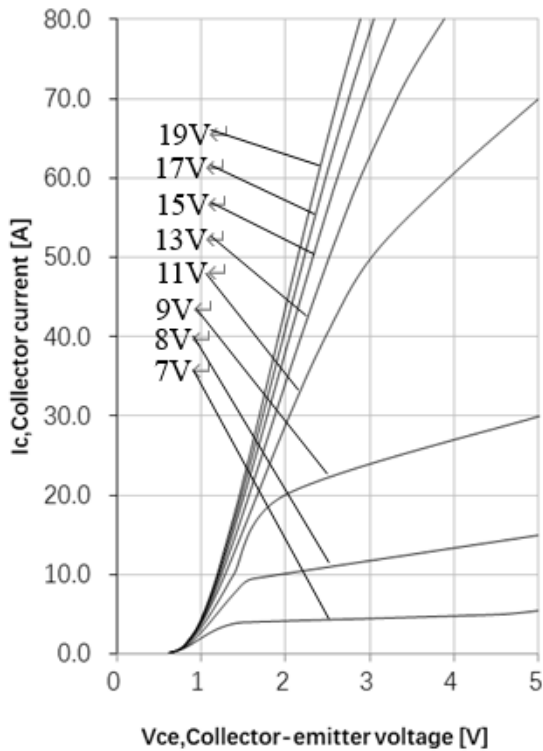


Fig3. Typical output characteristic ( $T_j = 25^\circ\text{C}$ )

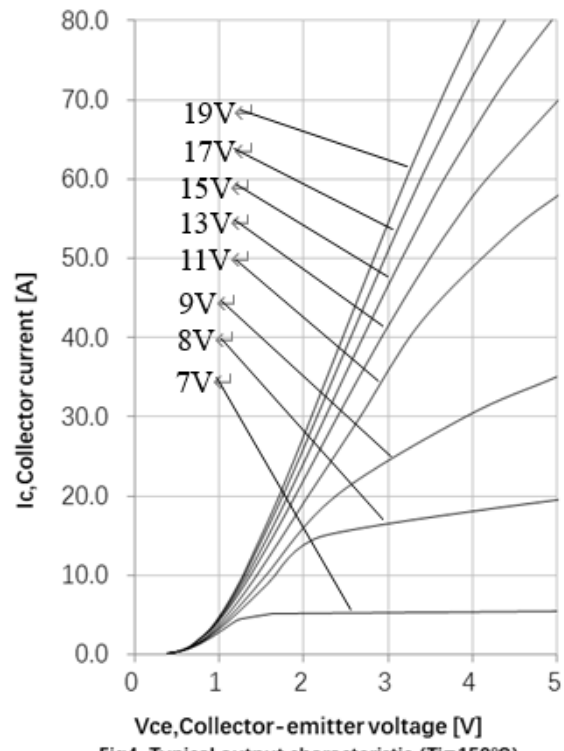


Fig4. Typical output characteristic ( $T_j = 150^\circ\text{C}$ )

Curve Characteristics

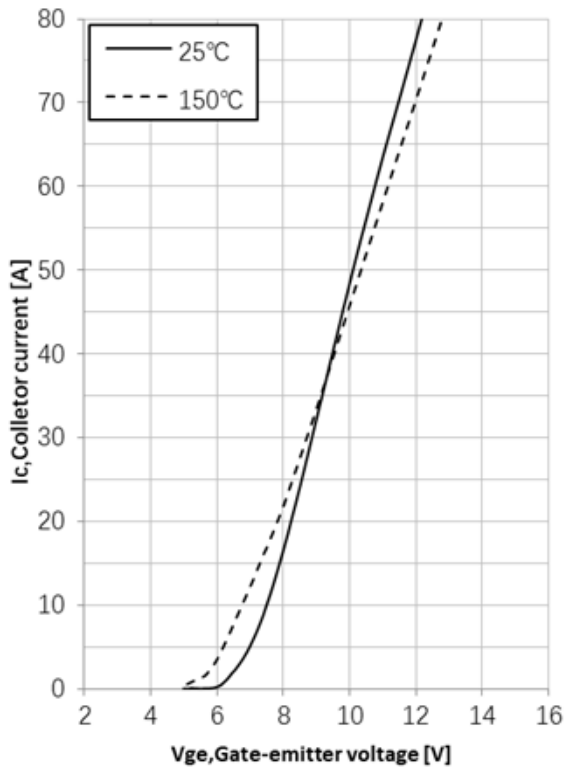


Fig5. Typical transfer characteristic (Vce=20V)

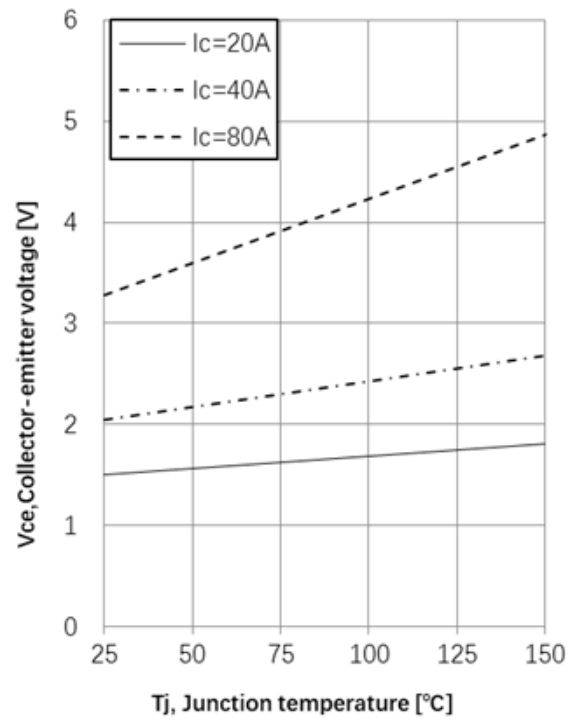


Fig6. Typical collector-emitter saturation voltage as a function of junction temperature (Vge=15V)

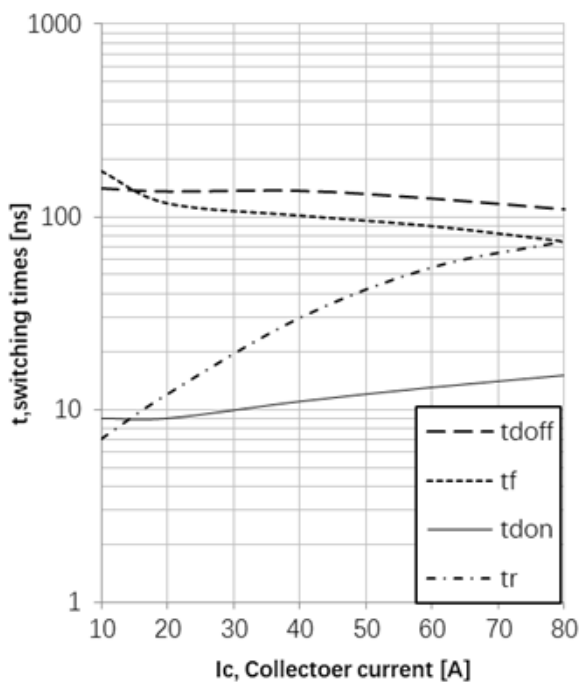


Fig7. Typical switching time as a function of collector current (inductive load, Tvj=150°C, Vce=400V, Vge=0/15V, Rg=10Ω)

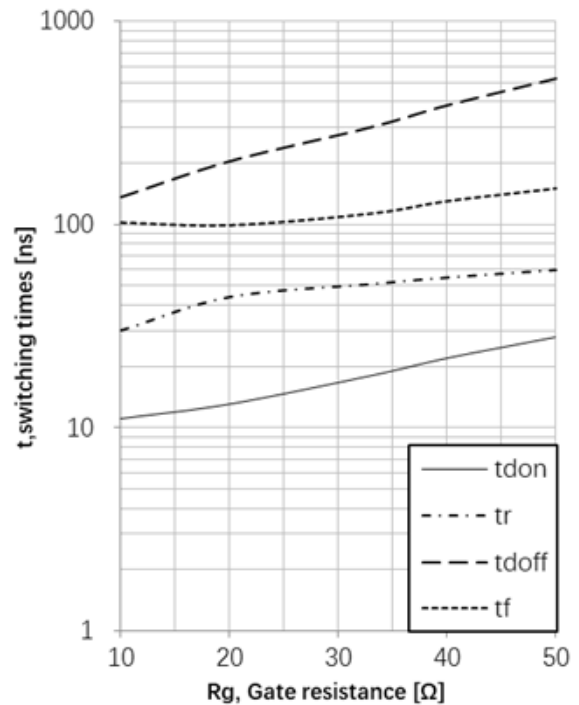


Fig8. Typical switching times as a function of gate resistance (inductive load, Tvj=150°C, Vce=400V, Vge=0/15V, Ic=40A)

Curve Characteristics

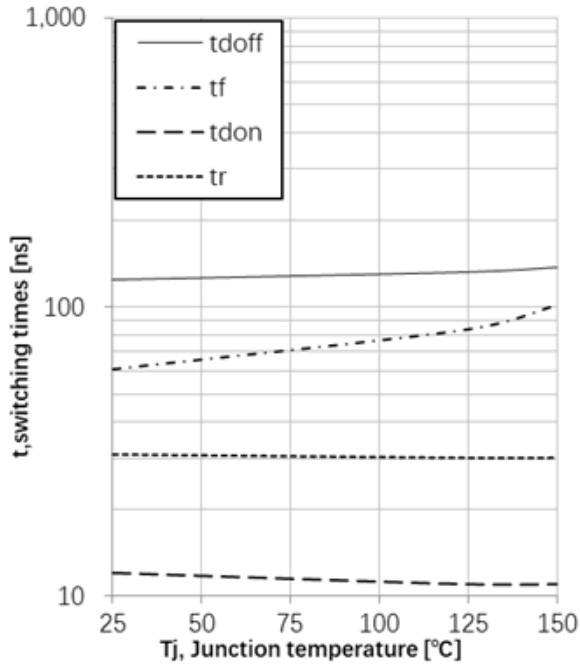


Fig9. Typical switching times as a function of junction temperature (inductive load, I<sub>c</sub>=40A, V<sub>ce</sub>=400V, V<sub>ge</sub>=0/15V, R<sub>g</sub>=10Ω)

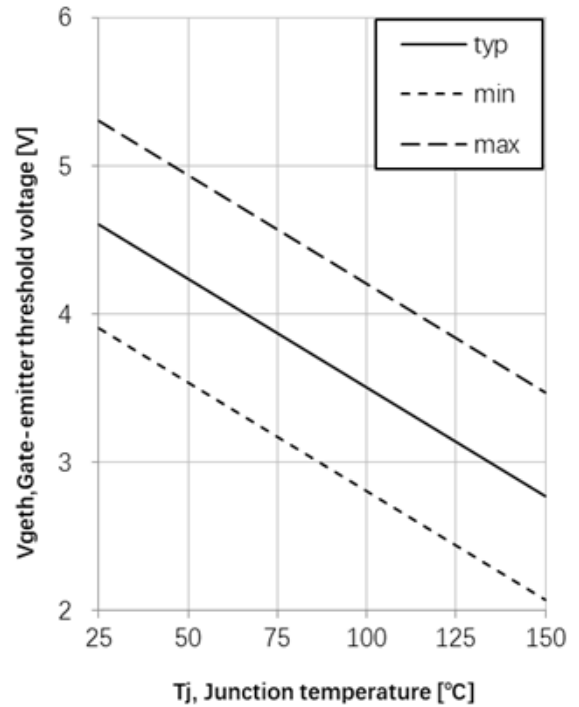


Fig10. Gate-emitter threshold voltage as a function of Junction temperature (I<sub>c</sub>=0.75mA)

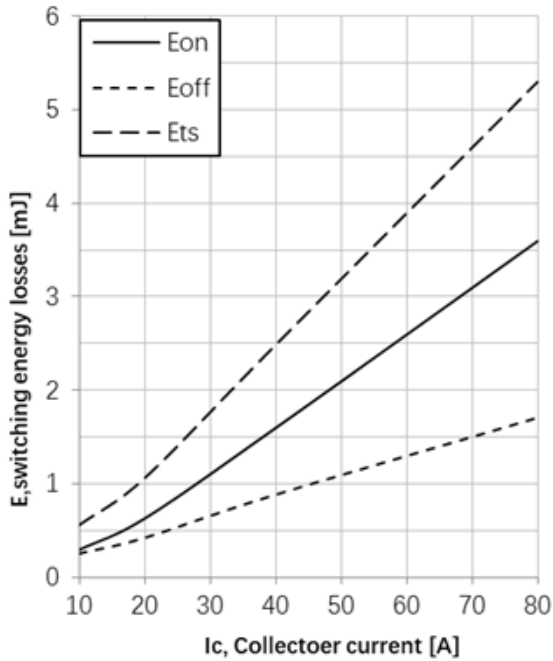


Fig11. Typical switching energy losses as a function of collect current (inductive load, T<sub>vj</sub>=150°C, V<sub>ce</sub>=400V, V<sub>ge</sub>=0/15V, R<sub>g</sub>=10Ω)

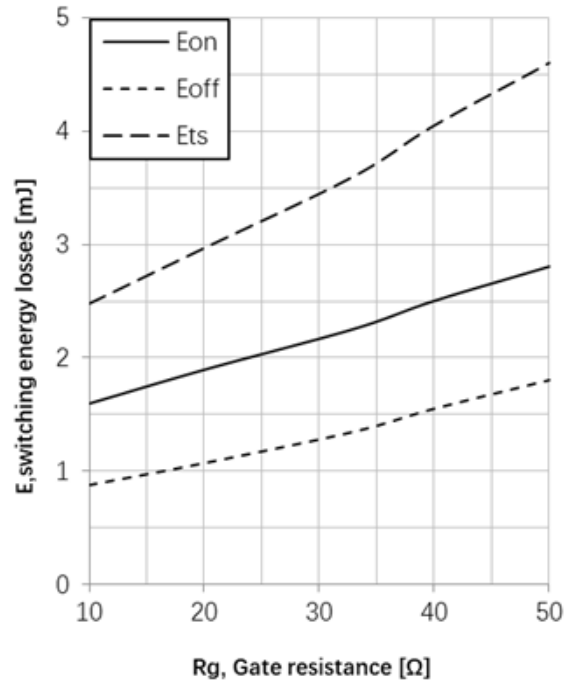


Fig12. Typical switching energy losses as a function of gate resistance (inductive load, T<sub>vj</sub>=150°C, V<sub>ce</sub>=400V, V<sub>ge</sub>=0/15V, I<sub>c</sub>=40A)

Curve Characteristics

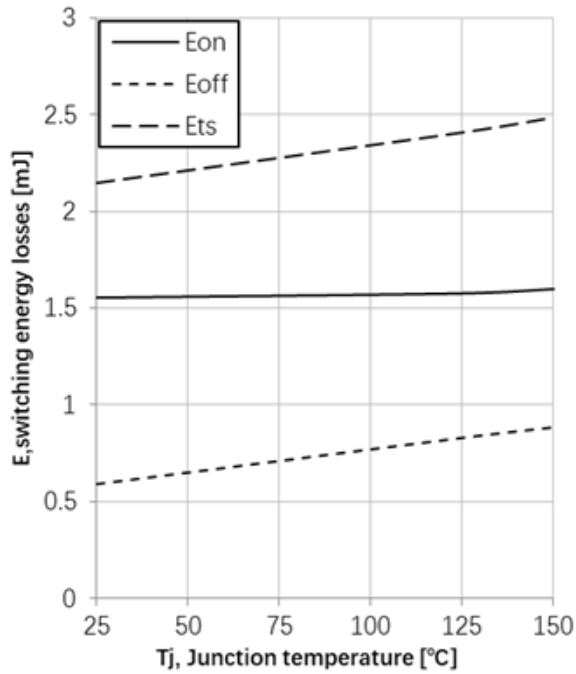


Fig13. Typical switching energy losses as a function of Junction temperature (inductive)  
load, I<sub>c</sub>=40A, V<sub>ce</sub>=400V, V<sub>ge</sub>=0/15V, R<sub>g</sub>=10Ω

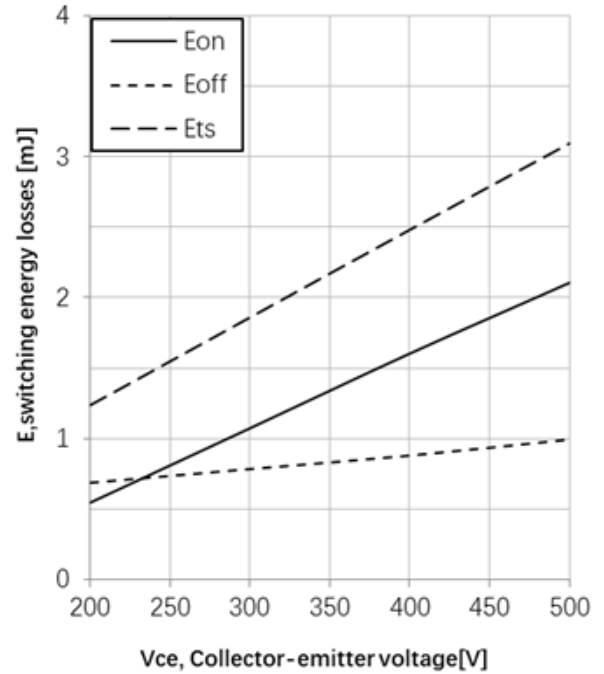


Fig14. Typical switching energy losses as a function of collector-emitter voltage (inductive)  
load, T<sub>vj</sub>=150°C, I<sub>c</sub>=40A, V<sub>ge</sub>=0/15V, R<sub>g</sub>=10Ω

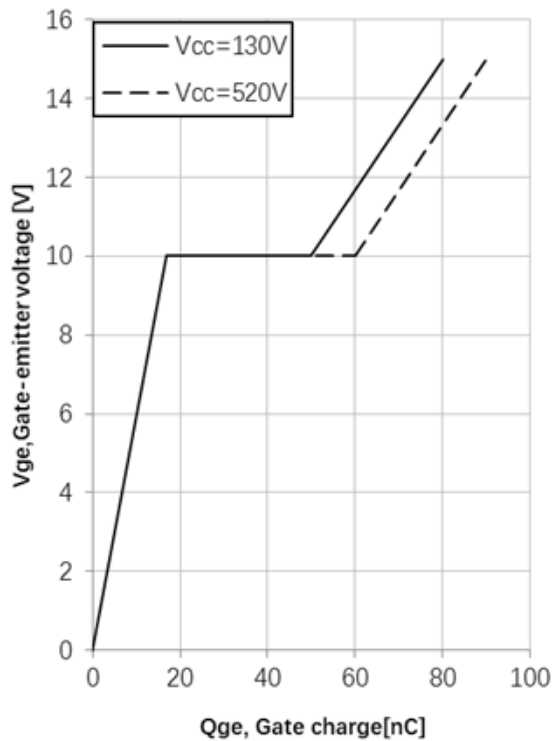


Fig15. Typical gate charge (I<sub>c</sub>=40A)

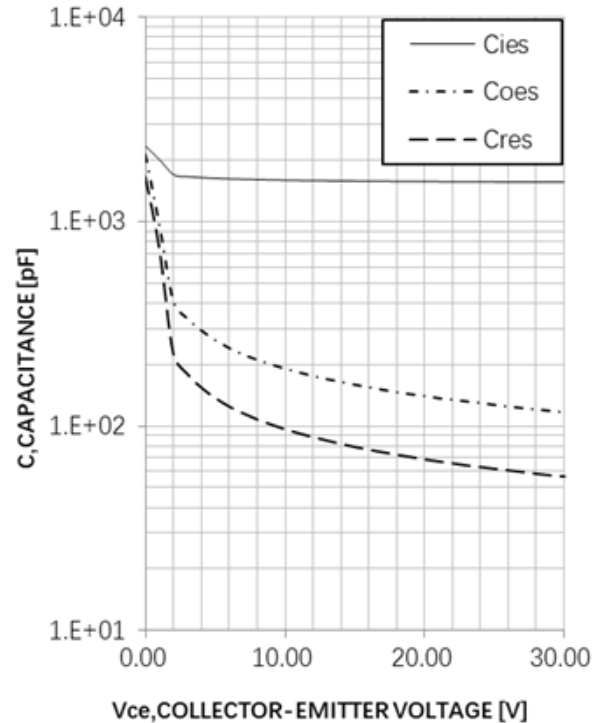


Fig16. Typical capacitance as a function of collector-emitter voltage

Curve Characteristics

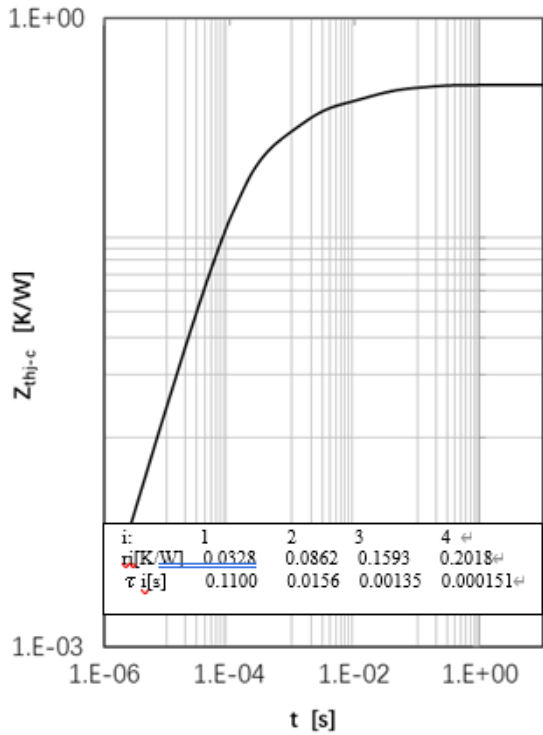


Fig 17. IGBT Transient Thermal Impedance

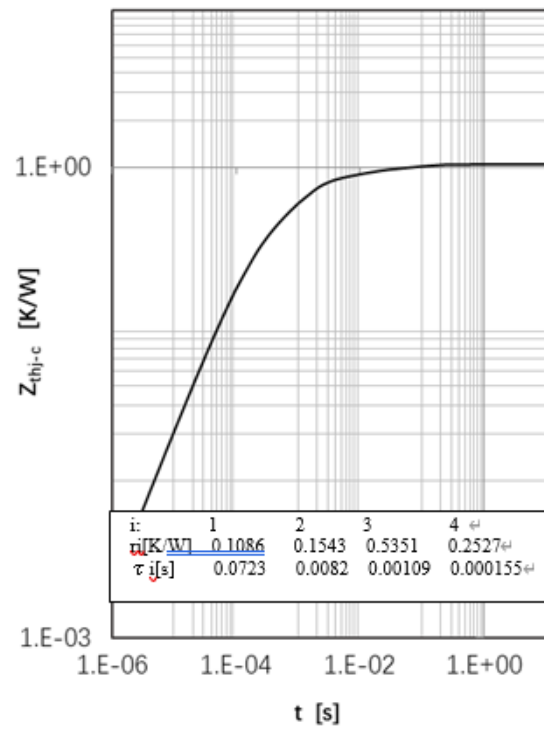


Fig 18. Diode Transient Thermal Impedance

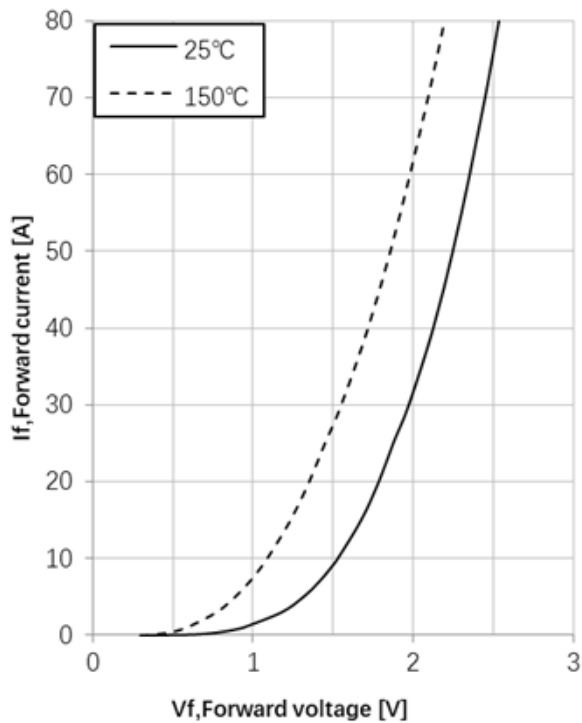


Fig19. Diode forward current as a function of forward voltage

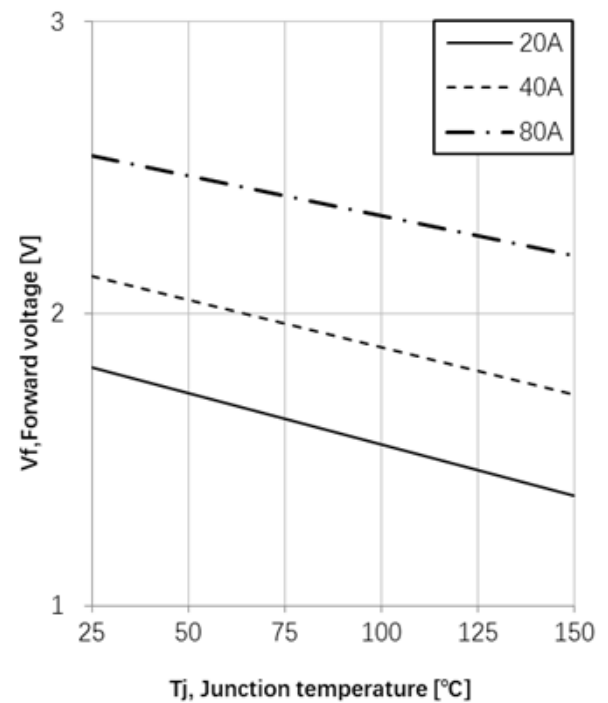
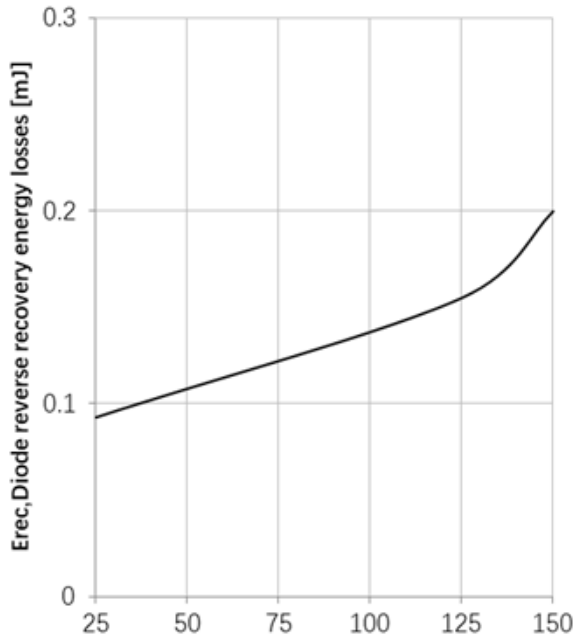


Fig20. Typical diode forward voltage as a function of Junction temperature

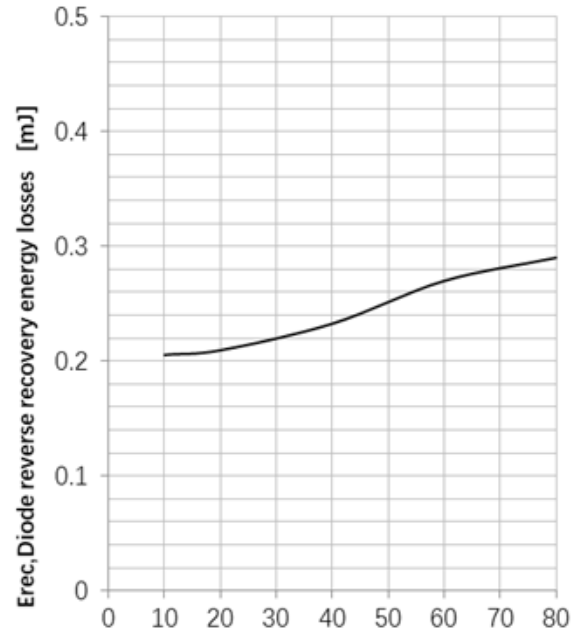


## Curve Characteristics



Tj, Junction temperature [°C]

Fig21. Typical diode reverse recovery energy losses as a function of Junction temperature (inductive load, If=40A, Vrr=400V)



If, Collector current [A]

Fig22. Typical diode reverse recovery energy losses as a function of collector current (inductive load, Tvj=150°C, Vrr=400V)

## Ordering Information

Device	Packing
Part Number-BP	Tube: 30pcs/Tube, 1800pcs/Ctn

**\*\*\*IMPORTANT NOTICE\*\*\***

*Micro Commercial Components Corp.* reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. *Micro Commercial Components Corp.* does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold *Micro Commercial Components Corp.* and all the companies whose products are represented on our website, harmless against all damages. *Micro Commercial Components Corp.* products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

**\*\*\*LIFE SUPPORT\*\*\***

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

**\*\*\*CUSTOMER AWARENESS\*\*\***

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.